









SN65176B, SN75176B

SLLS101H - JULY 1985 - REVISED DECEMBER 2021

# **SNx5176B Differential Bus Transceivers**

#### 1 Features

- Bidirectional transceivers
- Meet or exceed the requirements of ANSI standards TIA/EIA-422-B and TIA/EIA-485-A and ITU Recommendations V.11 and X.27
- Designed for multipoint transmission on long bus lines in noisy environments
- 3-State driver and receiver outputs
- Individual driver and receiver enables
- Wide positive and negative input/output bus voltage ranges
- ± 60-mA Maximum driver output capability
- Thermal shutdown protection
- Driver positive and negative current limiting
- 12-kΩ Minimum Receiver Input Impedance
- ± 200-mV Receiver input sensitivity
- 50-mV Typical receiver input hysteresis
- Operate from single 5-V supply

### 2 Applications

- Chemical and gas sensors
- Digital signage
- HMI (human machine interfaces)
- Motor controls: AC induction, brushed and brushless dc, low- and high-voltage, stepper motors, and permanent magnets
- **TETRA Base stations**
- Telecom towers: remote electrical tilt units (ret) and tower mounted amplifiers (TMA)
- Weigh scales
- Wireless repeaters

## 3 Description

The SN65176B and SN75176B differential bus transceivers are designed for bidirectional data communication on multipoint bus transmission lines. They are designed for balanced transmission lines and meet ANSI Standards TIA/EIA-422-B and TIA/ EIA-485-A and ITU Recommendations V.11 and X.27.

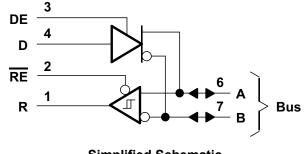
The SN65176B and SN75176B devices combine a 3-state differential line driver and a differential input line receiver, both of which operate from a single 5-V power supply. The driver and receiver have activehigh and active-low enables, respectively, that can be connected together externally to function as a direction control. The driver differential outputs and the receiver differential inputs are connected internally to form differential input/output (I/O) bus ports that are designed to offer minimum loading to the bus when the driver is disabled or  $V_{CC} = 0$ . These ports feature wide positive and negative common-mode voltage ranges, making the device suitable for partyline applications.

The driver is designed for up to 60 mA of sink or source current. The driver features positive and negative current limiting and thermal shutdown for protection from line-fault conditions. Thermal shutdown is designed to occur at a junction temperature of approximately 150°C. The receiver features a minimum input impedance of 12 k $\Omega$ , an input sensitivity of ±200 mV, and a typical input hysteresis of 50 mV.

#### **Device Information**

PART NUMBER	PACKAGE (PIN)(1)	BODY SIZE (NOM)
	SOIC (8)	4.90 mm × 3.91 mm
SNx5176	PDIP (8)	9.81 mm × 6.35 mm
	SOP (8)	6.20 mm × 5.30 mm

For all available packages, see the orderable addendum at the end of the datasheet.



Simplified Schematic



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# **5 Pin Configuration and Functions**

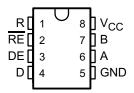


Figure 5-1. Top View

#### **Table 5-1. Pin Functions**

PIN		TYPE	DESCRIPTION	
NAME	NO.	ITPE	DESCRIPTION	
R	1	0	Logic Data Output from RS-485 Receiver	
RE	2	I	Receive Enable (active low)	
DE	3	I	Driver Enable (active high)	
D	4	I	Logic Data Input to RS-485 Driver	
GND	5	_	Device Ground Pin	
A	6	I/O	RS-422 or RS-485 Data Line	
В	7	I/O	RS-422 or RS-485 Data Line	
V <sub>CC</sub>	8	_	Power Input. Connect to 5-V Power Source.	



# **6 Specifications**

# **6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage <sup>(2)</sup>		7	V
	Voltage range at any bus terminal	-10	15	V
VI	Enable input voltage		5.5	V
T <sub>J</sub>	Operating virtual junction temperature		150	°C
T <sub>stg</sub>	Storage temperature range	-65	150	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		260	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Section 6.2 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

**6.2 Recommended Operating Conditions** 

			MIN	TYP	MAX	UNIT
V <sub>CC</sub>	Supply voltage		4.75	5	5.25	V
V <sub>I</sub> or V <sub>IC</sub>	Voltage at any bus terminal (separately	or common mode)	-7		12	V
V <sub>IH</sub>	High-level input voltage	D, DE, and RE	2			V
V <sub>IL</sub>	Low-level input voltage	D, DE, and RE			0.8	V
V <sub>ID</sub>	Differential input voltage <sup>(1)</sup>				±12	V
	High-level output current	Driver			-60	mA
I <sub>OH</sub>		Receiver			-400	μA
	Low-level output current	Driver			60	А
l <sub>OL</sub>		Receiver			8	mA
_	Operating free cir temperature	SN65176B	-40		105	°C
$T_A$	Operating free-air temperature	SN75176B	0		70	C

<sup>(1)</sup> Differential input/output bus voltage is measured at the non-inverting terminal A, with respect to the inverting terminal B.

#### **6.3 Thermal Information**

			SNx5176			
	THERMAL METRIC(1)	D (SOIC)	PS (SO)	P (PDIP)	UNIT	
			8 PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	114.4	113.2	88.1	°C/W	
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	55.1	57.9	65.9	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	61.6	69.0	69.0	°C/W	
ΨЈТ	Junction-to-top characterization parameter	8.8	14.6	35.2	°C/W	
$\Psi_{JB}$	Junction-to-board characterization parameter	60.8	68.1	64.3	°C/W	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

<sup>(2)</sup> All voltage values, except differential input/output bus voltage, are with respect to network ground terminal.



#### 6.4 Electrical Characteristics - Driver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CON	IDITIONS <sup>(1)</sup>	MIN	TYP <sup>(2)</sup>	MAX	UNIT
V <sub>IK</sub>	Input clamp voltage	I <sub>I</sub> = -18 mA				-1.5	V
Vo	Output voltage	I <sub>O</sub> = 0		0		Vcc	V
V <sub>OD1</sub>	Differential output voltage	I <sub>O</sub> = 0		1.5	3.6	Vcc	V
IV/ I	Differential output voltage	$R_L$ = 100 Ω, see Figur	re 7-1	½ V <sub>OD1</sub> or 2 <sup>(4)</sup>			V
V <sub>OD2</sub>	Dillerential output voltage	$R_L$ = 54 Ω, see Figure	7-1	1.5	2.5	5	V
V <sub>OD3</sub>	Differential output voltage	See <sup>(5)</sup>		1.5		5	V
$\Delta  V_{OD} $	Change in magnitude of differential output voltage <sup>(3)</sup>	$R_L$ = 54 Ω or 100 Ω, s	ee Figure 7-1			±0.2	V
Voc	Common-mode output voltage	$R_L$ = 54 Ω or 100 Ω, s	ee Figure 7-1	-1		+3	V
Δ V <sub>OC</sub>	Change in magnitude of common-mode output voltage <sup>(3)</sup>	$R_L = 54 \Omega \text{ or } 100 \Omega, \text{ s}$	ee Figure 7-1			±0.2	V
	Output current	Output disabled <sup>(6)</sup>	V <sub>O</sub> = 12 V			1	mA
IO	Output current	Output disabled	V <sub>O</sub> = -7 V			-0.8	ША
I <sub>IH</sub>	High-level input current	V <sub>I</sub> = 2.4 V				20	μA
I <sub>IL</sub>	Low-level input current	V <sub>I</sub> = 0.4 V				-400	μA
		V <sub>O</sub> = -7 V				-250	
	Short-circuit output current	V <sub>O</sub> = 0				-150	mA
I <sub>OS</sub>	Short-circuit output current	V <sub>O</sub> = V <sub>CC</sub>				250	ША
		V <sub>O</sub> = 12 V				250	
	Cumply ourrant (total postessa)	No load	Outputs enabled		42	70	mΛ
I <sub>CC</sub>	Supply current (total package)	No load	Outputs disabled		26	35	mA

<sup>(1)</sup> The power-off measurement in ANSI Standard TIA/EIA-422-B applies to disabled outputs only and is not applied to combined inputs and outputs.

<sup>(2)</sup> All typical values are at  $V_{CC} = 5 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$ .

<sup>(3)</sup>  $\Delta |V_{OD}|$  and  $\Delta |V_{OC}|$  are the changes in magnitude of  $V_{OD}$  and  $V_{OC}$ , respectively, that occur when the input is changed from a high level to a low level

<sup>(4)</sup> The minimum  $V_{OD2}$  with a 100- $\Omega$  load is either ½  $V_{OD1}$  or 2 V, whichever is greater.

<sup>(5)</sup> See ANSI Standard TIA/EIA-485-A, Figure 3.5, Test Termination Measurement 2.

<sup>(6)</sup> This applies for both power on and off; refer to ANSI Standard TIA/EIA-485-A for exact conditions. The TIA/EIA-422-B limit does not apply for a combined driver and receiver terminal.

#### 6.5 Electrical Characteristics - Receiver

over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST C	CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
V <sub>IT+</sub>	Positive-going input threshold voltage	$V_O = 2.7 \text{ V}, I_O = -0.4 \text{ mA}$				0.2	V
V <sub>IT</sub> _	Negative-going input threshold voltage	V <sub>O</sub> = 0.5 V, I <sub>O</sub> = 8 mA		-0.2 <sup>(2)</sup>			V
V <sub>hys</sub>	Input hysteresis voltage (V <sub>IT+</sub> – V <sub>IT-</sub> )				50		mV
V <sub>IK</sub>	Enable Input clamp voltage	I <sub>I</sub> = -18 mA				-1.5	V
V <sub>OH</sub>	High-level output voltage	V <sub>ID</sub> = 200 mV, I <sub>OH</sub> = -400	μA, see Figure 7-2	2.7			V
V <sub>OL</sub>	Low-level output voltage	V <sub>ID</sub> = -200 mV, I <sub>OL</sub> = 8 m	A, see Figure 7-2			0.45	V
I <sub>OZ</sub>	High-impedance-state output current	V <sub>O</sub> = 0.4 V to 2.4 V				±20	μA
	15	Oth an impact (0.17(3))	V <sub>I</sub> = 12 V			1	4
l <sub>l</sub>	Line input current	Other input = 0 V <sup>(3)</sup>	V <sub>I</sub> = -7 V			-0.8	mA
I <sub>IH</sub>	High-level enable input current	V <sub>IH</sub> = 2.7 V				20	μA
I <sub>IL</sub>	Low-level enable input current	V <sub>IL</sub> = 0.4 V				-100	μA
rı	Input resistance	V <sub>I</sub> = 12 V		12			kΩ
Ios	Short-circuit output current			-15		-85	mA
	Owner to a summer to the test of the section and	N. I I	Outputs enabled		42	55	
I <sub>CC</sub>	Supply current (total package)	No load	Outputs disabled		26	35	mA

<sup>(1)</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

### 6.6 Switching Characteristics - Driver

 $V_{CC}$  = 5 V,  $R_L$  = 110  $\Omega$ ,  $T_A$  = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>d(OD)</sub>	Differential-output delay time	$R_L = 54 \Omega$ , see Figure 7-3		15	22	ns
t <sub>t(OD)</sub>	Differential-output transition time	$R_L = 54 \Omega$ , see Figure 7-3		20	30	ns
t <sub>PZH</sub>	Output enable time to high level	See Figure 7-4		85	120	ns
t <sub>PZL</sub>	Output enable time to low level	See Figure 7-5		40	60	ns
t <sub>PHZ</sub>	Output disable time from high level	See Figure 7-4		150	250	ns
t <sub>PLZ</sub>	Output disable time from low level	See Figure 7-5		20	30	ns

# 6.7 Switching Characteristics – Receiver

 $V_{CC} = 5 \text{ V}, C_L = 15 \text{ pF}, T_A = 25^{\circ}\text{C}$ 

	, L 1 , A					
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>PLH</sub>	Propagation delay time, low- to high-level output	V <sub>ID</sub> = 0 to 3 V, see Figure 7-6		21	35	no
t <sub>PHL</sub>	Propagation delay time, high- to low-level output	V <sub>ID</sub> – 0 to 3 v, see Figure 7-0		23	35	ns
t <sub>PZH</sub>	Output enable time to high level	See Figure 7-7		10	20	no
t <sub>PZL</sub>	Output enable time to low level	See Figure 7-7		12	20	ns
t <sub>PHZ</sub>	Output disable time from high level	See Figure 7.7		20	35	
t <sub>PLZ</sub>	Output disable time from low level	See Figure 7-7		17	25	ns

<sup>(2)</sup> The algebraic convention, in which the less positive (more negative) limit is designated minimum, is used in this data sheet for common-mode input voltage and threshold voltage levels only.

<sup>(3)</sup> This applies for both power on and power off. Refer to EIA Standard TIA/EIA-485-A for exact conditions.

#### 6.8 Typical Characteristics

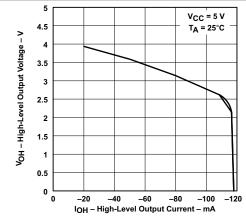


Figure 6-1. Driver High-Level Output Voltage vs High-Level Output Current

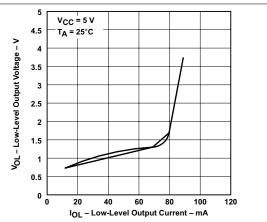


Figure 6-2. Driver Low-Level Output Voltage vs Low-Level Output Current

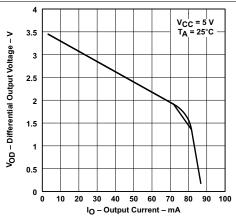


Figure 6-3. Driver Differential Output Voltage vs Output Current

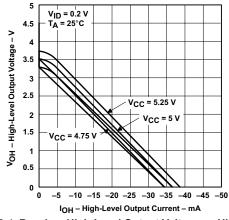
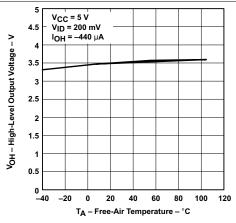


Figure 6-4. Receiver High-Level Output Voltage vs High-Level Output Current



Only the 0°C to 70°C portion of the curve applies to the SN75176B device.

Figure 6-5. Receiver High-Level Output Voltage vs Free-Air Temperature

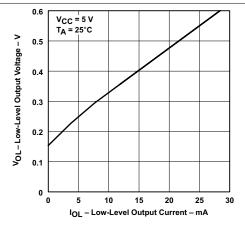
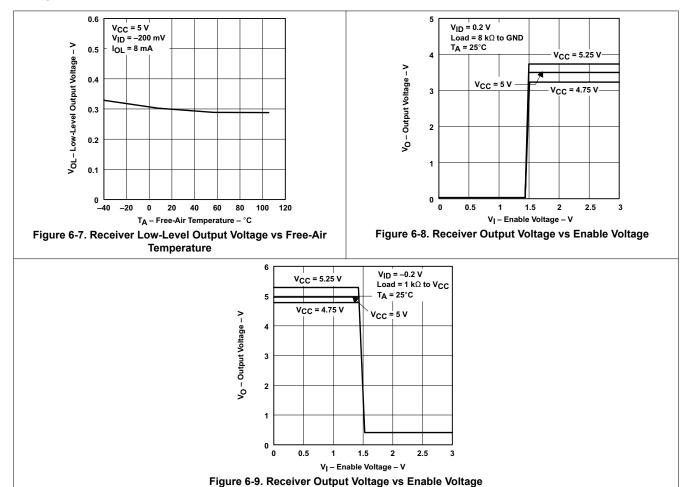


Figure 6-6. Receiver Low-Level Output Voltage vs Low-Level Output Current



### **6.8 Typical Characteristics (continued)**





### **Parameter Measurement Information**

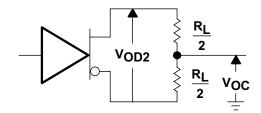


Figure 7-1. Driver V<sub>OD</sub> and V<sub>OC</sub>

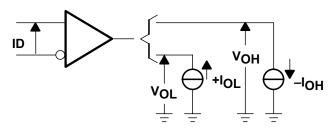
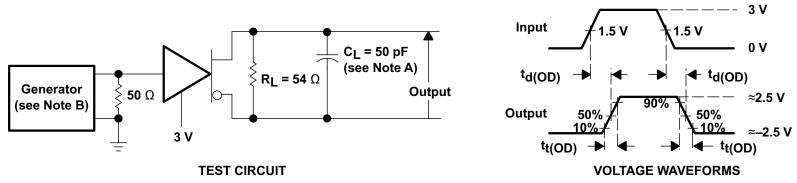
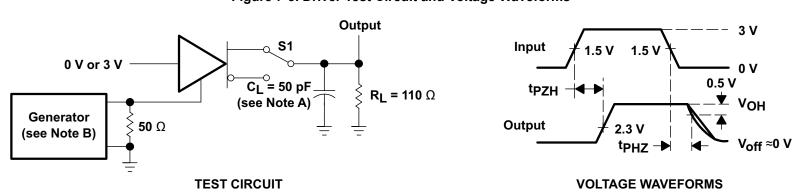


Figure 7-2. Receiver  $V_{OH}$  and  $V_{OL}$ 



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$ 1 MHz, 50% duty cycle,  $t_r \leq$  6 ns,  $t_f \leq$  6 ns,  $t_O =$  50  $t_O =$  50.

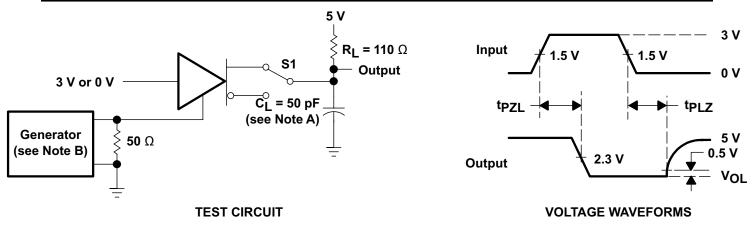
Figure 7-3. Driver Test Circuit and Voltage Waveforms



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$ 1 MHz, 50% duty cycle,  $t_r \leq$  6 ns,  $t_f \leq$  6 ns,  $t_Q =$  50  $t_Q =$  50

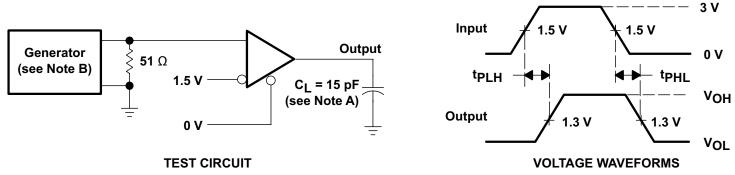
Figure 7-4. Driver Test Circuit and Voltage Waveforms





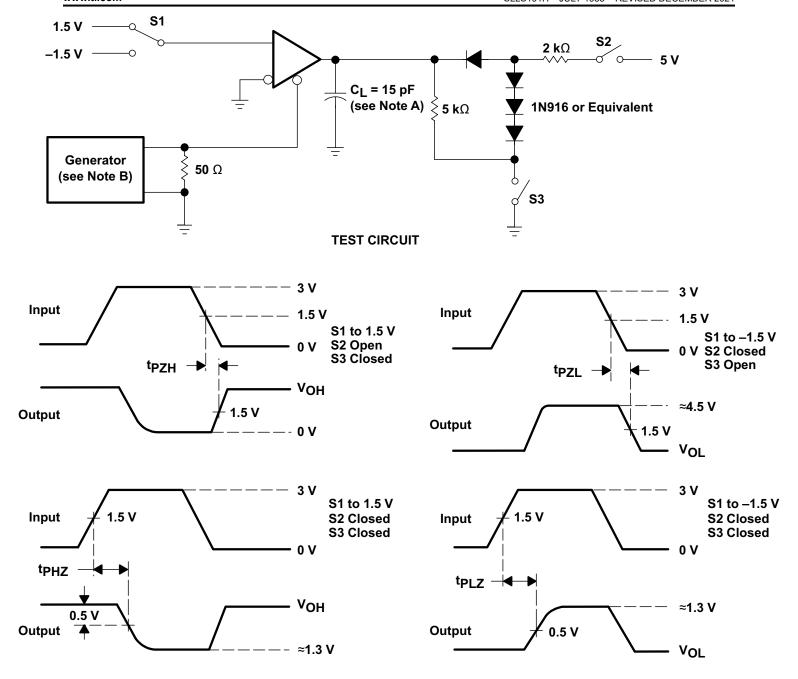
- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR ≤1 MHz, 50% duty cycle, t<sub>r</sub> ≤ 6 ns, t<sub>f</sub> ≤ 6 ns, Z<sub>O</sub> = 50

Figure 7-5. Driver Test Circuit and Voltage Waveforms



- A. C<sub>I</sub> includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$ 1 MHz, 50% duty cycle,  $t_r \leq$  6 ns,  $t_f \leq$  6 ns,  $t_Q =$  50  $t_Q =$  50

Figure 7-6. Receiver Test Circuit and Voltage Waveforms



#### **VOLTAGE WAVEFORMS**

- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$ 1 MHz, 50% duty cycle,  $t_r \leq$  6 ns,  $t_f \leq$  6 ns,  $t_Q =$  50  $t_Q =$  50

Figure 7-7. Receiver Test Circuit and Voltage Waveforms

### 7 Detailed Description

#### 7.1 Overview

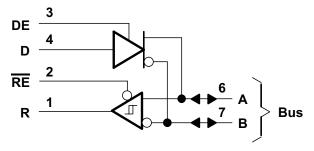
The SN65176B and SN75176B differential bus transceivers are integrated circuits designed for bidirectional data communication on multipoint bus transmission lines. They are designed for balanced transmission lines and meet ANSI Standards TIA/EIA-422-B and TIA/EIA-485-A and ITU Recommendations V.11 and X.27.

The SN65176B and SN75176B devices combine a 3-state differential line driver and a differential input line receiver, both of which operate from a single 5-V power supply. The driver and receiver have active-high and active-low enables, respectively, that can be connected together externally to function as a direction control. The driver differential outputs and the receiver differential inputs are connected internally to form differential input/output (I/O) bus ports that are designed to offer minimum loading to the bus when the driver is disabled or  $V_{CC} = 0$ . These ports feature wide positive and negative common-mode voltage ranges, making the device suitable for party-line applications.

The driver is designed for up to 60 mA of sink or source current. The driver features positive and negative current limiting and thermal shutdown for protection from line-fault conditions. Thermal shutdown is designed to occur at a junction temperature of approximately  $150^{\circ}$ C. The receiver features a minimum input impedance of 12 k $\Omega$ , an input sensitivity of  $\pm 200$  mV, and a typical input hysteresis of 50 mV.

The SN65176B and SN75176B devices can be used in transmission-line applications employing the SN75172 and SN75174 quadruple differential line drivers and SN75173 and SN75175 quadruple differential line receivers.

#### 7.2 Functional Block Diagram



#### 7.3 Feature Description

#### 7.3.1 Driver

The driver converts a TTL logic signal level to RS-422 and RS-485 compliant differential output. The TTL logic input, DE pin, can be used to turn the driver on and off.

Table 7-1. Driver Function Table (1)

INPUT	ENABLE	DIFFERENT	IAL OUTPUTS
D	DE	Α	В
Н	Н	Н	L
L	Н	L	Н
X	L	Z	Z

(1) H = high level,

L = low level,

X = irrelevant,

Z = high impedance (off)



#### 7.3.2 Receiver

The receiver converts a RS-422 or RS-485 differential input voltage to a TTL logic level output. The TTL logic input,  $\overline{\text{RE}}$  pin, can be used to turn the receiver logic output on and off.

Table 7-2. Receiver Function Table (1)

DIFFERENTIAL INPUTS A-B	ENABLE RE	OUTPUT R
V <sub>ID</sub> ≥ 0.2 V	L	Н
-0.2 V < V <sub>ID</sub> < 0.2 V	L	U
V <sub>ID</sub> ≤ -0.2 V	L	L
X	н	Z
Open	L	U

<sup>(1)</sup> H = high level,

### 7.4 Device Functional Modes

#### 7.4.1 Device Powered

Both the driver and receiver can be individually enabled or disabled in any combination. DE and  $\overline{RE}$  can be connected together for a single port direction control bit.

#### 7.4.2 Device Unpowered

The driver differential outputs and the receiver differential inputs are connected internally to form differential input/output (I/O) bus ports that are designed to offer minimum loading to the bus when the driver is disabled or  $V_{CC} = 0$ .

#### 7.4.3 Symbol Cross Reference

Table 7-3. Symbol Equivalents

DATA SHEET PARAMETER	TIA/EIA-422-B	TIA/EIA-485-A						
Vo	V <sub>oa</sub> , V <sub>ob</sub>	$V_{oa}, V_{ob}$						
V <sub>OD1</sub>	V <sub>o</sub>	V <sub>o</sub>						
V <sub>OD2</sub>	V <sub>t</sub> ® <sub>L</sub> = 100 Ω)	V <sub>t</sub> ® <sub>L</sub> = 54 Ω)						
V <sub>OD3</sub>		V <sub>t</sub> (test termination measurement 2)						
$\Delta  V_{OD} $	$   V_t  -   \overline{V}_t   $	$   V_t -   \overline{V}_t    $						
V <sub>OC</sub>	V <sub>os</sub>	V <sub>os</sub>						
Δ V <sub>OC</sub>	$ V_{os} - \overline{V}_{os} $	$ V_{os} - \overline{V}_{os} $						
I <sub>OS</sub>	I <sub>sa</sub>  ,  I <sub>sb</sub>							
Io	I <sub>xa</sub>  ,  I <sub>xb</sub>	I <sub>ia</sub> , I <sub>ib</sub>						

L = low level,

U = unknown,

Z = high impedance (off)

### 8 Application and Implementation

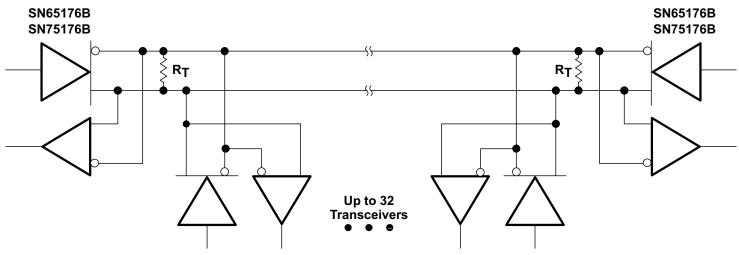
#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

#### **8.1 Application Information**

The device can be used in RS-485 and RS-422 physical layer communications.

#### 8.2 Typical Application



The line should be terminated at both ends in its characteristic impedance  $@_T = Z_O$ ). Stub lengths off the main line should be kept as short as possible.

Figure 8-1. Typical RS-485 Application Circuit

#### 8.2.1 Design Requirements

- 5-V power source
- RS-485 bus operating at 10 Mbps or less
- Connector that ensures the correct polarity for port pins
- · External fail safe implementation

#### 8.2.2 Detailed Design Procedure

- Place the device close to bus connector to keep traces (stub) short to prevent adding reflections to the bus line
- If desired, add external fail-safe biasing to ensure +200 mV on the A-B port.



#### 8.2.3 Application Curves

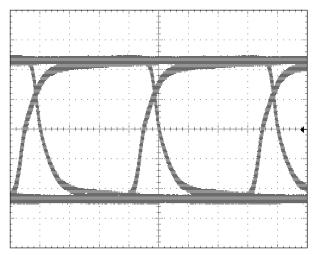


Figure 8-2. Eye Diagram for 10-Mbits/s over 100 feet of standard CAT-5E cable 120-Ω Termination at both ends. Scale is 1 V per division and 25 nS per division

# 8.3 System Examples

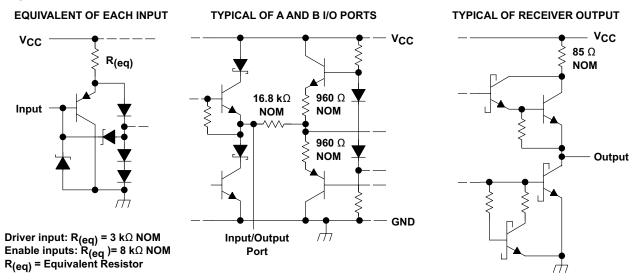


Figure 8-3. Schematics of Inputs and Outputs



# 9 Power Supply Recommendations

Power supply should be 5 V with a tolerance less than 10%

## 10 Layout

# 10.1 Layout Guidelines

Traces from device pins A and B to connector must be short and capable of 250 mA maximum current.

## 10.2 Layout Example

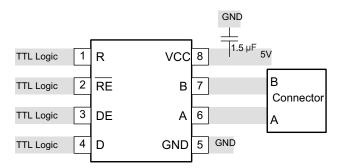


Figure 10-1. Layout Diagram

# 11 Device and Documentation Support

### 11.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 11-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN65176B	Click here	Click here	Click here	Click here	Click here
SN75176B	Click here	Click here	Click here	Click here	Click here

#### 11.2 Trademarks

All trademarks are the property of their respective owners.

#### 11.3 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 11.4 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN65176BDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	65176B	Samples
SN65176BDRE4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	65176B	Samples
SN65176BDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	65176B	Samples
SN65176BP	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 105	SN65176BP	Samples
SN75176BDG4	NRND				75	TBD	Call TI	Call TI	0 to 70		
SN75176BDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75176B	Samples
SN75176BDRE4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75176B	Samples
SN75176BDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75176B	Samples
SN75176BP	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75176BP	Samples
SN75176BPE4	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75176BP	Samples
SN75176BPSR	ACTIVE	so	PS	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	A176B	Samples
SN75176BPSRG4	ACTIVE	SO	PS	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	A176B	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



# PACKAGE OPTION ADDENDUM

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- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65176BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN65176BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN65176BDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75176BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75176BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75176BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75176BDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75176BPSR	so	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN75176BPSR	so	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1



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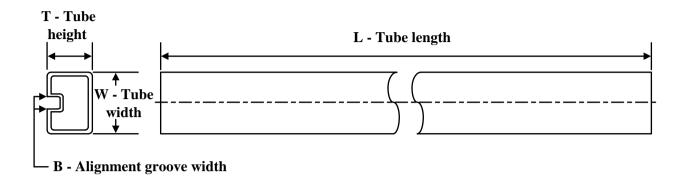
\*All dimensions are nominal

7 til dilliciololio die Hollindi							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65176BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN65176BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN65176BDRG4	SOIC	D	8	2500	356.0	356.0	35.0
SN75176BDR	SOIC	D	8	2500	367.0	367.0	35.0
SN75176BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN75176BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN75176BDRG4	SOIC	D	8	2500	367.0	367.0	35.0
SN75176BPSR	SO	PS	8	2000	367.0	367.0	38.0
SN75176BPSR	SO	PS	8	2000	356.0	356.0	35.0

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN65176BP	Р	PDIP	8	50	506	13.97	11230	4.32
SN75176BP	Р	PDIP	8	50	506	13.97	11230	4.32
SN75176BPE4	Р	PDIP	8	50	506	13.97	11230	4.32



SMALL OUTLINE INTEGRATED CIRCUIT



### NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# P (R-PDIP-T8)

# PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



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